Product Datasheet Product ID: BMBP22R2/R75-6PA



EC MICROWAVE

The door to the RF world

Thin Film ceramic Filte BMBP22R2/R75-6PA

Precautions

1. The chip is recommended sub-cavity use, both sides of the side wall from about 0.2mm, surface distance Cover about 3mm, the chip ports are interchangeable;

2. Chip recommended low-stress conductive adhesive (such as ME8456) bonding;

3. Chip should be installed in Kovar (recommended) or molybdenum copper with ceramic thermal expansion coefficient(6.7ppm / °C) on the carrier, the carrier thickness \geq 0.2mm;

4 circuit board micro-chip wire bonding connection, it is recommended microstrip bonding at mining T-type structure to match, T-size as right

Features

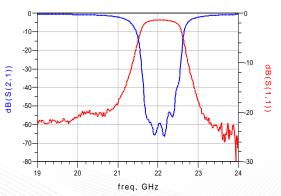
high-precision film processing technology
high performance, low temperature drift, high power
Ceramic substrate, 50Ω coplanar waveguide output
Gold wire bonding, suitable for multi-chip integrated module applications

Environmental parameters

Working temperature	-55°C~+85°C
storage temperature	-55°C~+125°C
Maximum input power	35dBm

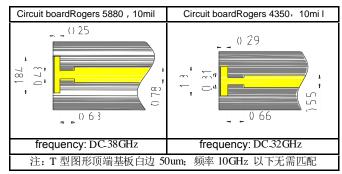
Electrical Specifications

Center frequency(f0)	19.7	
Passband frequency range (GHz)	18.0-21.4	
Band fluctuations (dB)	1	
Center insertion loss (dB)	2.5	
Return loss (dB)	15	
Band attenuation (dB)	≥ 40@ 14.9 GHz ≥ 40@23.4GHz	

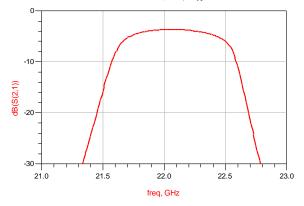


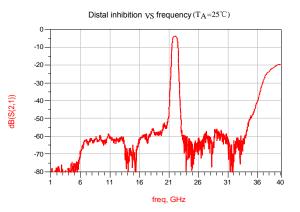
Band rejection & Return loss $\rm VS$ frequency $(T_A\!=\!\!25^\circ\!{\rm C\,})$

1/1HORN ANTENNAS Rev JUN-2017



Passband loss VS frequency (T $A=25^{\circ}C$)





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